

Silicon Carbide Power MOSFET E-Series Automotive N-Channel Enhancement Mode

Features

- 3rd generation SiC MOSFET technology
- Optimized package with separate driver source pin
- 8mm of creepage distance between drain and source
- High blocking voltage with low on-resistance
- High-speed switching with low capacitances
- Fast intrinsic diode with low reverse recovery (Q_r)
- Halogen free, RoHS compliant
- Automotive Qualified (AEC-Q101) and PPAP Capable

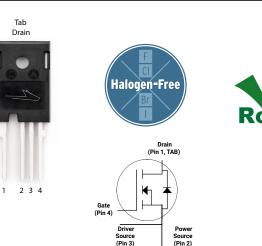
Benefits

- Reduce switching losses and minimize gate ringing
- Higher system efficiency
- Reduce cooling requirements
- Increase power density
- Increase system switching frequency

Applications

- EV Battery Chargers
- High Voltage DC/DC Converters





Part Number	Package	Marking		
E3M0060065K	TO-247-4L	E3M0060065K		

Maximum Ratings ($T_c = 25$ °C unless otherwise specified)

Symbol	Parameter	Value	Unit	Note	
V _{DSmax}	Drain - Source Voltage		650	V	
V_{GSmax}	Gate - Source Voltage		-8/+19	V	Note: 1
		$T_C = 25^{\circ}C$	37		Fig. 19
I _D	Continuous Drain Current, V _{GS} = 15 V		26		Note: 2
I _{D(pulse)}	Pulsed Drain Current, Pulse width t _p limited by T _{jmax}	99	А	Fig. 22	
P _D	Power Dissipation, $T_c = 25^{\circ}C$, $T_j = 175^{\circ}C$	131	w	Fig. 20 Note: 2	
T _J , T _{stg}	, T _{stg} Operating Junction and Storage Temperature			°C	
T	Solder Temperature, 1.6mm (0.063") from case for 10s			°C	
M _d	Mounting Torque , M3 or 6-32 screw			Nm Ibf-in	

Note (1): Recommended turn off / turn on gate voltage V_{GS} - 4V...0V / +15V Note (2): Verified by design

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Symbol	Parameter	Min.	Тур.	Max.	Unit	Test Conditions	Note	
$V_{\text{(BR)DSS}}$	Drain-Source Breakdown Voltage	650			V	$V_{GS} = 0 V, I_D = 100 \mu A$		
M	V Cata Throshold Voltage	1.8	2.8	3.6	V	$V_{DS} = V_{GS}$, $I_D = 3.6 \text{ mA}$		
$V_{GS(th)}$	Gate Threshold Voltage		2.2		V	$V_{DS} = V_{GS}$, $I_D = 3.6$ mA, $T_J = 175^{\circ}C$		
I _{DSS}	Zero Gate Voltage Drain Current		1	50	μA	$V_{\text{DS}} = 650 \text{ V}, V_{\text{GS}} = 0 \text{ V}$		
I _{GSS}	Gate-Source Leakage Current		10	250	nA	$V_{GS} = 15 \text{ V}, V_{DS} = 0 \text{ V}$		
R _{DS(on)}	Drain-Source On-State Resistance		60	79	mΩ	$V_{GS} = 15 \text{ V}, I_D = 13.2 \text{ A}$	Fig. 4,	
• •DS(on)			83			$V_{GS} = 15 \text{ V}, I_D = 13.2 \text{ A}, T_J = 175^{\circ}\text{C}$	5,6	
g _{fs}	Transconductance		9		s	V_{DS} = 20 V, I_{DS} = 13.2 A	Fig. 7	
515			9			V_{DS} = 20 V, I_{DS} = 13.2 A, T_J = 175°C		
C _{iss}	Input Capacitance		1170					
C _{oss}	Output Capacitance		72		pF	$V_{\text{GS}}=0$ V, $V_{\text{DS}}=0V$ to 600 V	Fig. 17, 18	
C _{rss}	Reverse Transfer Capacitance		6	1	1	F = 1 Mhz		
Eoss	Coss Stored Energy	+ +	14	1	μJ	$V_{AC} = 25 \text{ mV}$	Eig 16	
							Fig. 16	
C _{o(er)}	Effective Output Capacitance (Energy Related)		85		pF	$V_{GS} = 0 V, V_{DS} = 0 400V$	Note: 3	
$C_{o(tr)}$	Effective Output Capacitance (Time Related)		122		pF			
E _{ON}	Turn-On Switching Energy (External Diode)		29			$V_{DS} = 400 \text{ V}, V_{GS} = -4 \text{ V}/15 \text{ V}, I_{D} = 13.2 \text{ A},$	Fig. 25	
E _{OFF}	Turn Off Switching Energy (External Diode)		12		μJ	$R_{G(ext)} = 2.5 \Omega$, L= 135 μH, T _J = 175°C FWD = External SiC DIODE		
E _{ON}	Turn-On Switching Energy (Body Diode FWD)		40			$V_{DS} = 400 \text{ V}, V_{GS} = -4 \text{ V}/15 \text{ V}, I_{D} = 13.2\text{ A},$	Fig. 25	
E _{OFF}	Turn-Off Switching Energy (Body Diode FWD)		11		μJ	$R_{G(ext)} = 2.5 \Omega$, L= 135 μ H, T _J = 175°C FWD = Internal Body Diode		
t _{d(on)}	Turn-On Delay Time		9				Fig. 26	
tr	Rise Time		10			$\begin{split} V_{\text{DD}} &= 400 \text{ V}, V_{\text{GS}} = -4 \text{ V}/15 \text{ V} \\ I_{\text{D}} &= 13.2 \text{ A}, R_{\text{G}(\text{ext})} = 2.5 \Omega, \end{split}$		
$t_{d(off)}$	Turn-Off Delay Time		16		ns	Timing relative to V _{DS} Inductive load		
t _f	Fall Time		8]			
$R_{G(int)}$	Internal Gate Resistance		4		Ω	$f = 1 MHz$, $V_{AC} = 25 mV$		
Q_{gs}	Gate to Source Charge		16			$V_{DS} = 400 \text{ V}, \text{ V}_{GS} = -4 \text{ V}/15 \text{ V}$		
Q_{gd}	Gate to Drain Charge		16		nC	I _D = 13.2 A	Fig. 12	
Qg	Total Gate Charge		49			Per IEC60747-8-4 pg 21		

Electrical Characteristics ($T_c = 25^{\circ}C$ unless otherwise specified)

Note (3): $C_{o(er)}$, a lumped capacitance that gives same stored energy as Coss while Vds is rising from 0 to 400V $C_{o(tr)}$, a lumped capacitance that gives same charging time as Coss while Vds is rising from 0 to 400V



Reverse Diode Characteristics ($T_c = 25^{\circ}C$ unless otherwise specified)

Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note
V	Diode Forward Voltage	4.6		V	$V_{_{GS}} = -4 V, I_{_{SD}} = 6.6 A, T_{_{J}} = 25 \text{ °C}$	Fig. 8, 9, 10
V _{SD}		4.1		V	$V_{_{GS}} = -4 V$, $I_{_{SD}} = 6.6 A$, $T_{_{J}} = 175 \ ^{\circ}C$	
ls	Continuous Diode Forward Current		23	А	$V_{GS} = -4 V, T_C = 25^{\circ}C$	
I _{S, pulse}	Diode pulse Current		99	А	$V_{GS} = -4 V$, pulse width t_P limited by T_{jmax}	
t _{rr}	Reverse Recover time	12		ns		
Q _{rr}	Reverse Recovery Charge	173		nC	$V_{GS} = -4 V, I_{SD} = 13.2 A, V_{R} = 400 V$ dif/dt = 4770 A/µs, T _J = 175 °C	
I _{rrm}	Peak Reverse Recovery Current	28		А		
t _{rr}	Reverse Recover time	15		ns		
Q _{rr}	Reverse Recovery Charge	122		nC	$V_{gs} = -4 V, I_{sD} = 13.2 A, V_{R} = 400 V$ dif/dt = 2200 A/µs, T _j = 175 °C	
I _{rrm}	Peak Reverse Recovery Current	13		A		

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note
R _{θJC}	Thermal Resistance from Junction to Case	1.02	1.14	°C/W		Fig. 21



Typical Performance

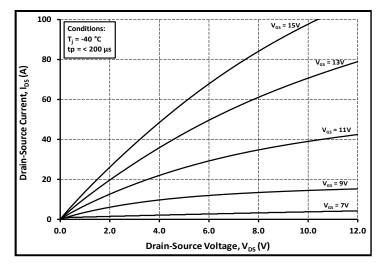
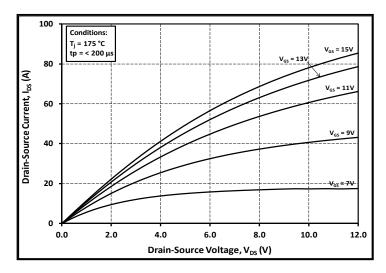


Figure 1. Output Characteristics T_J = -40 °C





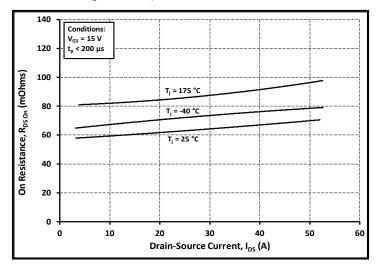
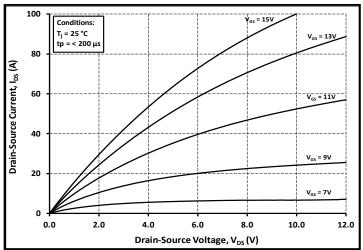
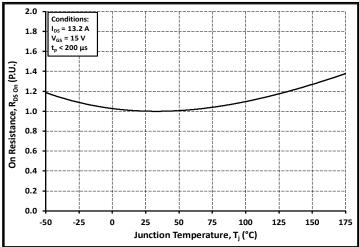


Figure 5. On-Resistance vs. Drain Current For Various Temperatures









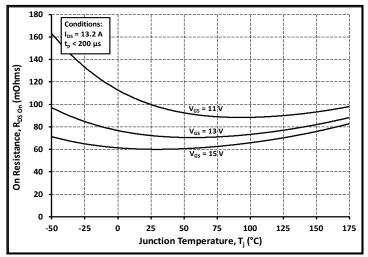


Figure 6. On-Resistance vs. Temperature For Various Gate Voltage

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Typical Performance

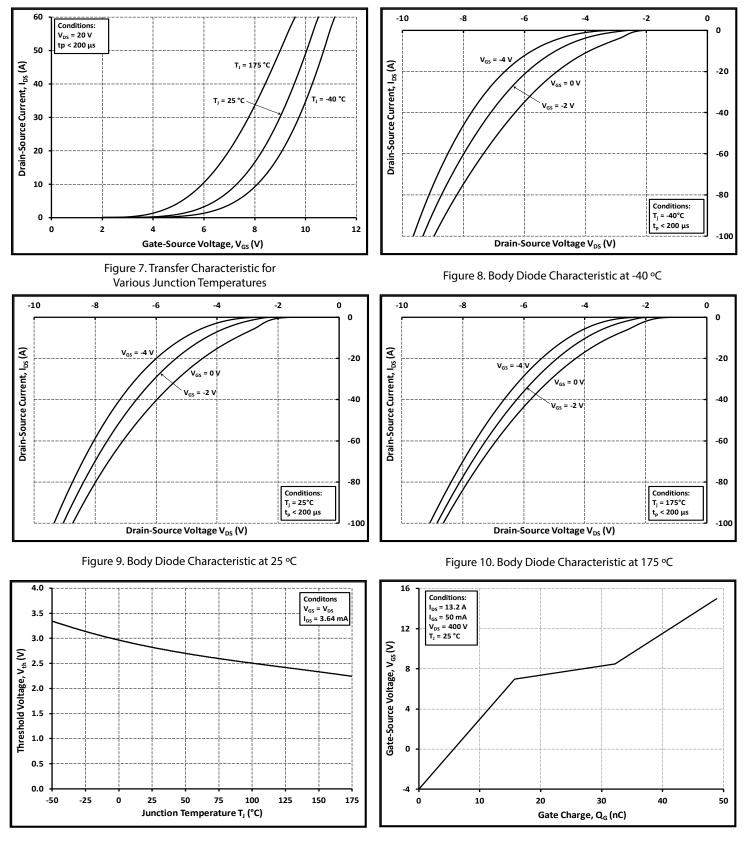


Figure 11. Threshold Voltage vs. Temperature

Figure 12. Gate Charge Characteristics

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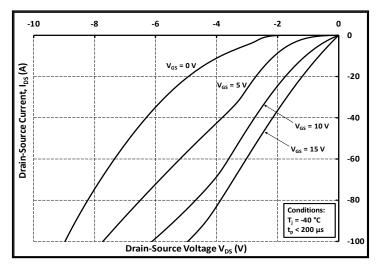


Figure 13. 3rd Quadrant Characteristic at -40 °C

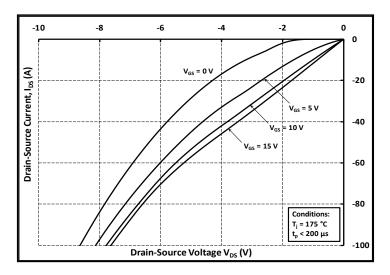
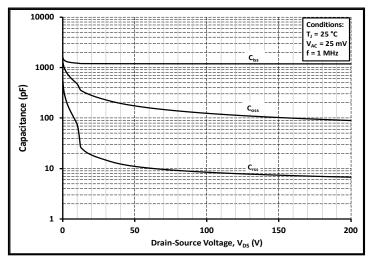
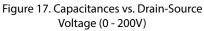


Figure 15. 3rd Quadrant Characteristic at 175 °C





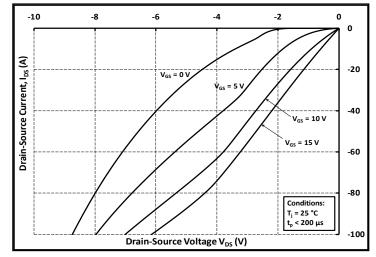


Figure 14. 3rd Quadrant Characteristic at 25 °C

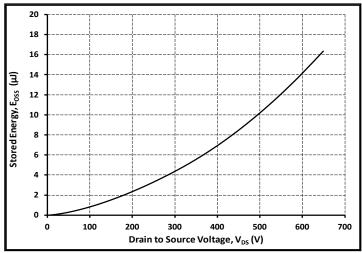


Figure 16. Output Capacitor Stored Energy

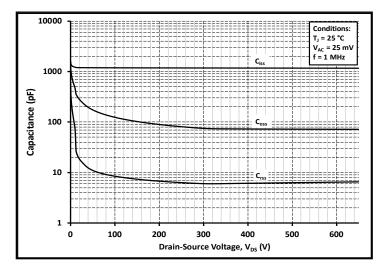


Figure 18. Capacitances vs. Drain-Source Voltage (0 - 650V)

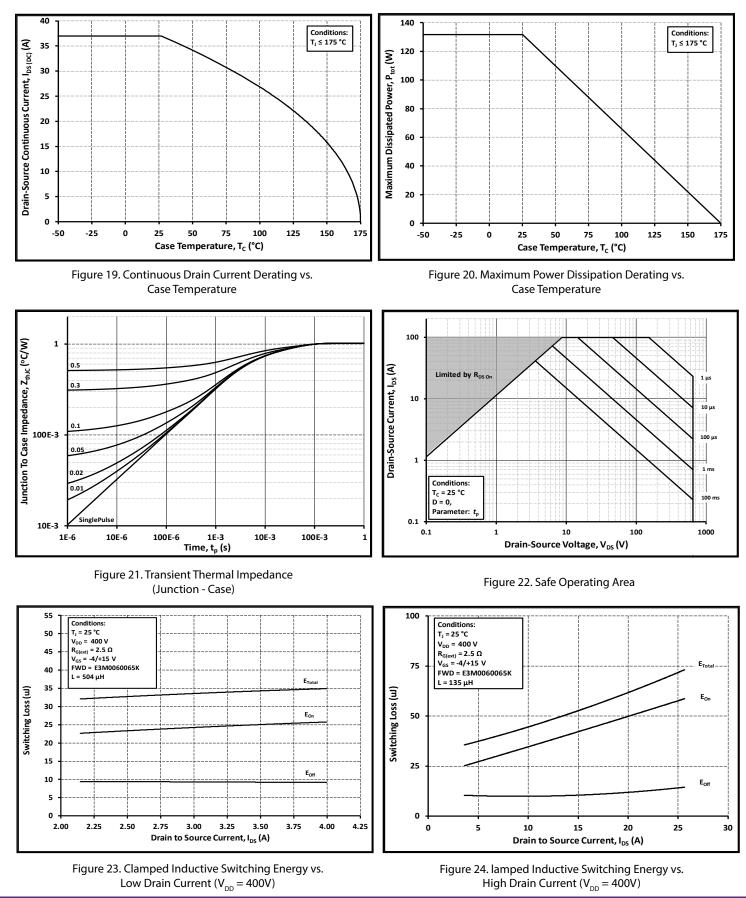
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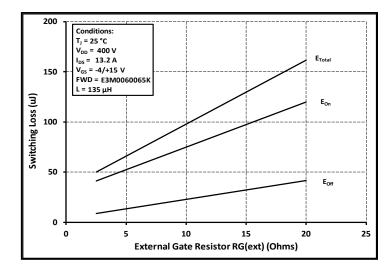
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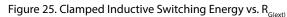
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Typical Performance





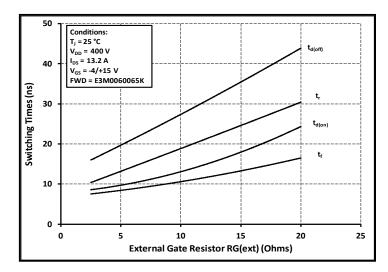


Figure 27. Switching Times vs. $R_{G(ext)}$

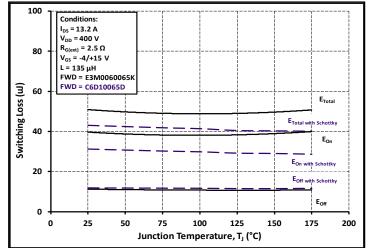


Figure 26. Clamped Inductive Switching Energy vs. Temperature

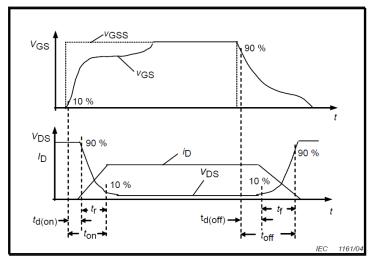


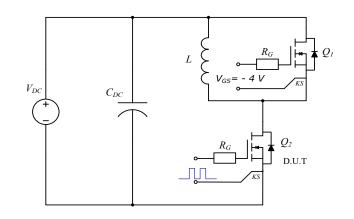
Figure 28. Switching Times Definition

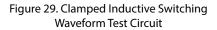
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Test Circuit Schematic



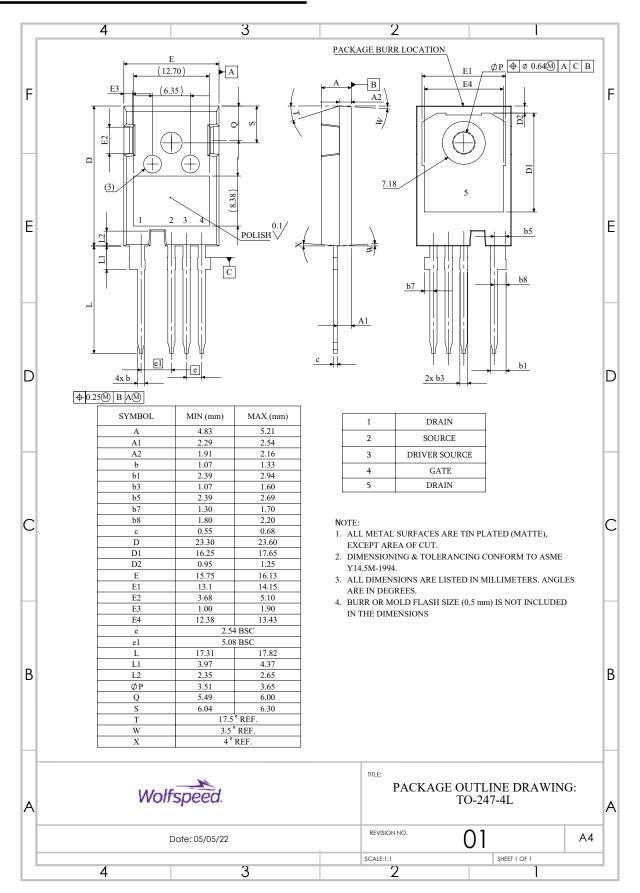




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Package Dimensions



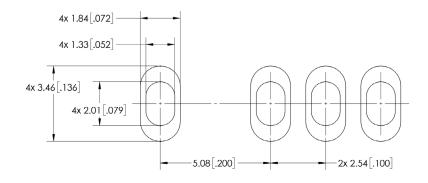
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Recommended Solder Pad Layout



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Revision history

Document Version	Date of release	Descriptiion of changes
1.0	June-2022	Initial datasheet

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